

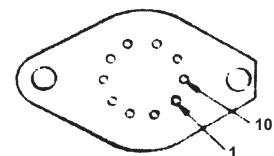
HYBRID DUAL POWER DRIVER

The MCH2890 dual Power Driver is capable of driving a wide variety of inductive and resistive loads, included are hammer solenoids in high-speed digital printers, paper-tape punchers and stepper motors in computer operated plotters.

- High Current - to 6.0 Amperes
- High Breakdown Voltage $BV_{CEX} = 120V$ min.
- MTTL Compatibility
- Separate Integrated Circuit and Darlington Power Grounds
- Low V_{sat} at 3.0 and 6.0 Amperes
- Low Leakage Current - $0.1 \mu A$ typ

DUAL POWER DRIVER

HYBRID SILICON INTEGRATED CIRCUIT



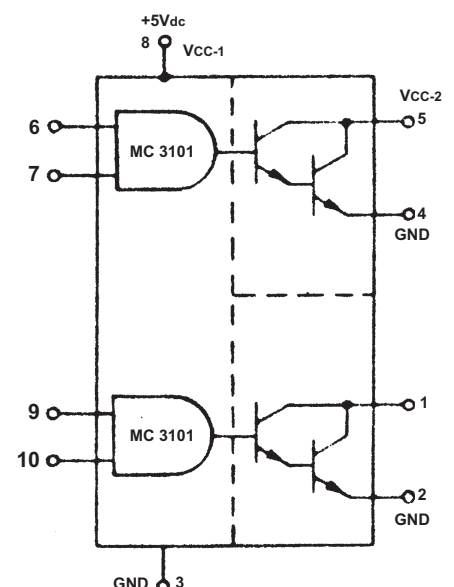
bottom view



CASE 685
METAL PACKAGE

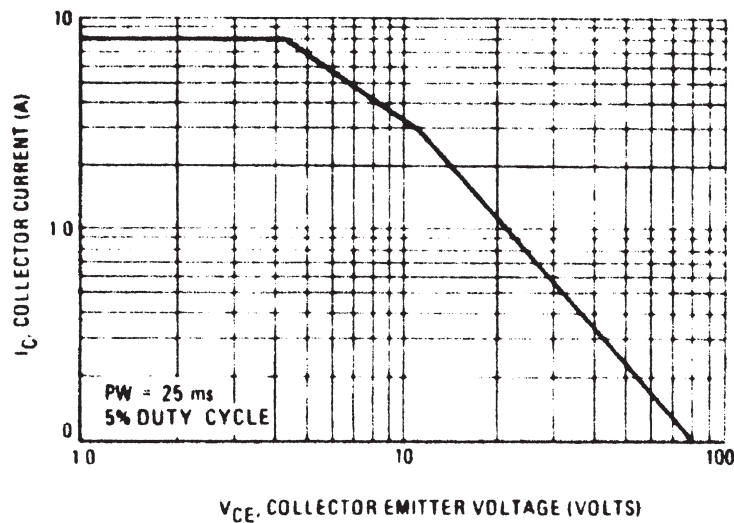
MAXIMUM RATINGS ($T_A = +25^\circ C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector current	I_C	8.0	A
		1.0	
Peak			
Continuous			
Collector Emitter Breakdown Voltage Minimum at $I_C < 0.5$ mA	BV_{CEX} (pins 1, 5)	120	V_{dc}
Power Supply Voltage (Integrated Circuit)	V_{CC1}	7.0	V_{dc}
Power Dissipation and Thermal Characteristics $T_A = 25^\circ C$ Derate above $T_A = 25^\circ C$ Thermal Resistance Junction to air $T_C = 25^\circ C$ Derate above $T_C = 25^\circ C$ Thermal Resistance Junction to Case	P_D	3.75	Watts
	$1/J_A$	25	$mW/^\circ C$
	$1/J_A$	40	$^\circ C/W$
	P_D	25	Watts
	$1/J_C$	167	$mW/^\circ C$
	$1/J_C$	6.0	$^\circ C/W$
Operating Temperature Range	T_A	0 to +70	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to +175	$^\circ C$



SAFE OPERATING AREA (Continued)

**FIGURE 7 – COLLECTOR-EMITTER VOLTAGE
VERSUS COLLECTOR CURRENT**



APPLICATIONS INFORMATION

The MCH2890 is designed for high-current and high-voltage applications such as hammer drivers in high-speed printers, relay drivers, lamp drivers, paper tape punches, stepping motors, and other high current inductive and resistive loads.

This dual hybrid driver, which consists of a monolithic MTL "AND" gate and two power Darlington drivers, is capable of supplying up to 6.0 amperes at a maximum duty cycle of 10% with pulse widths up to 25 ms. In addition to the high-current drive capability the MCH2890 offers high collector-to-emitter breakdown ($BV_{CEX} = 120$ Volts min) which is desirable when driving inductive loads at high currents.

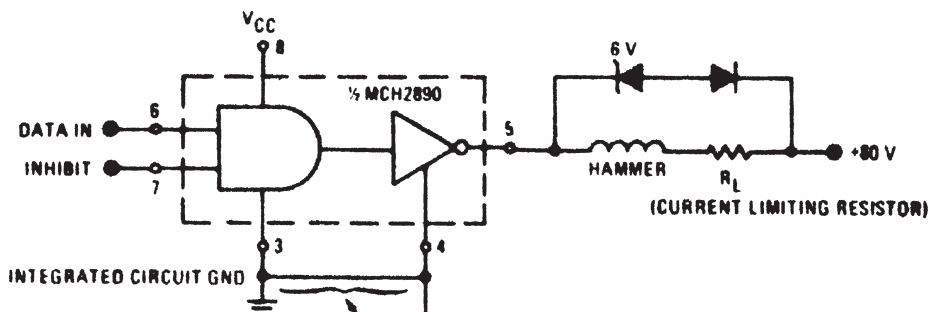
A typical high speed hammer driver application is illustrated in Figure 8. The number of drivers per printer is large, and considerable electrical noise is generated when they are switched simultaneously. The ground line, which terminates all of the Darlington power drivers, may be several feet in length resulting in substantial inductance and series resistance. The effect of this inductance and resistance becomes appreciable at the high-current

levels required of hammer drivers. When the Darlington power drivers are switched "off", even a small inductance at the Darlington ground generates a negative voltage spike which tends to turn the Darlington power driver "on" rather than "off". This negative excursion of the emitter can result in oscillations. The oscillation can be stopped by tying the integrated circuit ground (pin 3) to the Darlington ground (pins 2 and 4) with as short a line as possible. (See Figure 8). This circuit configuration pulls the gate output lower when the negative spike is present on the power ground line which guarantees "turn off" of the Darlington power driver.

To insure that the Darlington power driver does not go into secondary breakdown and latch up, a diode clamp is employed as shown. For high-speed printers, the addition of a zener diode can aid in dissipating the stored inductive power (during "turn off") in the hammer solenoid.

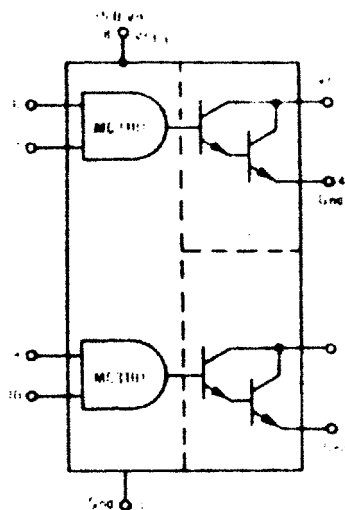
Additional features of the MCH2890 include fast switching and low leakage for minimum standby power.

FIGURE 8 – TYPICAL HAMMER DRIVER APPLICATION



The Darlington power driver ground should be connected to the integrated circuit ground with a short line. Ground to other Darlington power drivers.

Test procedures are shown for only one power driver. The other power driver is tested in the same manner.



0 °C 25 °C 75 °C	AMPERES		mA			VOLTS									
	IOL1	IOL2	Iin	ID	IC(max))	VIH	VIL	VF	VR	Vcc1	Vcc2	VCCIL	VCCIH	VRH	
	-	-	-	-	-	2.0	-	0.4	-	5.0	-	4.5	5.5	4.0	
	3.0	6.0	1.0	10	0.5	1.8	1.1	0.4	2.4	5.0	90	4.5	5.5	4.0	
	-	-	-	-	-	1.8	-	0.4	-	5.0	-	4.5	5.5	4.0	
TEST CURRENT/VOLTAGE APPLIED TO PNS BELOW															
Unit	IOL1	IOL2	Iin	ID	IC(max)	VIH	VIL	VF	VR	Vcc1	Vcc2	VCCIL	VCCIH	VRH	GND
mAdc								6				8		7	2,3,4
μAdc									6				8		2,3,4
Vdc			6										8		2,3,4
Vdc				6								8			2,3,4
Vdc	5 --	- 5 -			- - 5	6 - -		- - 6						7 7 7	2,3,4 2,3,4 2,3,4
μAdc											5			7	2,3,4
mAdc										8					2,3,4 6,7,9 10
mAdc										8				6,7,9 10	2,3,4
μS μS	5 5		Pulse In 6 6	Pulse Out 5 5						8 8				7 7	2,3,4 2,3,4

TEST CIRCUITS

FIGURE 1 - V_{OL} TEST CIRCUIT

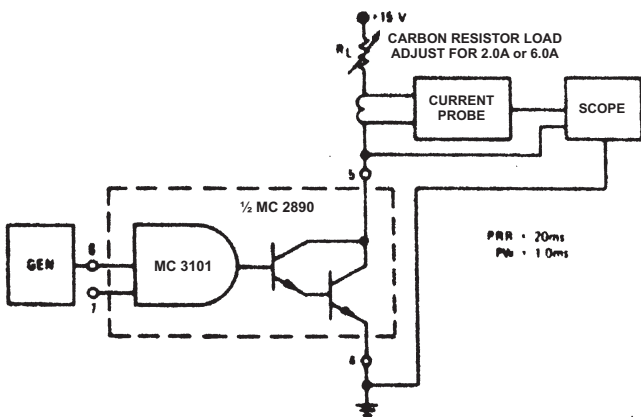
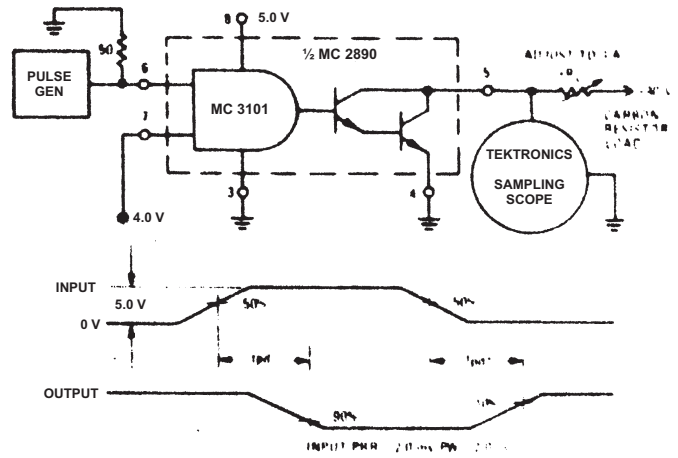


FIGURE 2 - PROPAGATION DELAY TIME TEST CIRCUIT



TYPICAL CHARACTERISTICS

FIGURE 3 - COLLECTOR-EMITTER VOLTAGE
VERSUS NEGATIVE EMITTER VOLTAGE

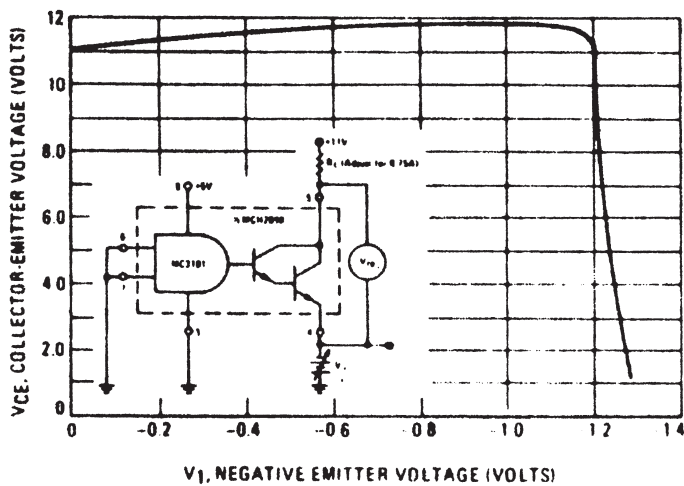
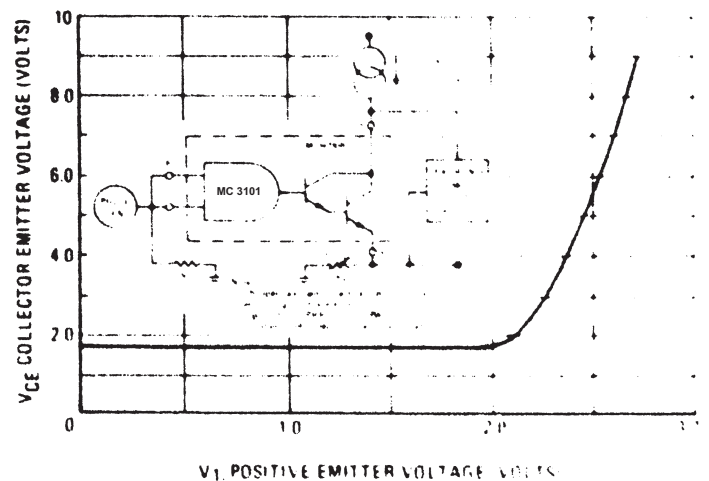


FIGURE 4 - COLLECTOR-EMITTER VOLTAGE
VERSUS POSITIVE EMITTER VOLTAGE



SAFE OPERATING AREA

FIGURE 5 - COLLECTOR-EMITTER VOLTAGE
VERSUS COLLECTOR CURRENT

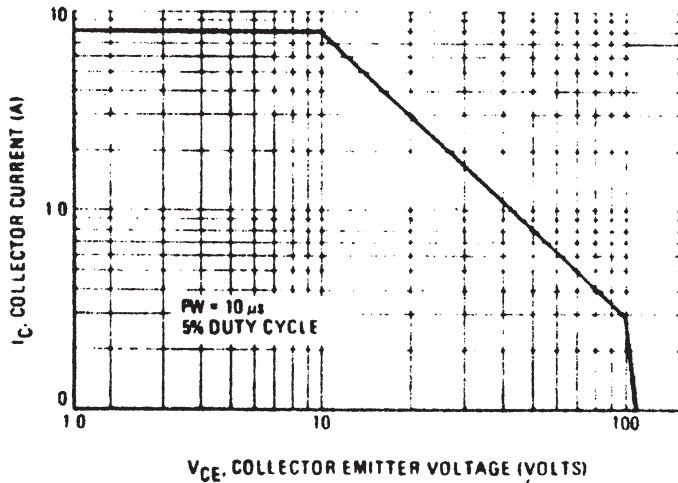


FIGURE 6 - COLLECTOR-EMITTER VOLTAGE
VERSUS COLLECTOR CURRENT

